ANALYSIS OF C-SHAPE COMPACT MICROSTIP LINE FED RECTANGULAR PATCH ANTENNA FOR DUALBAND OPERATION

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Abstract - In the paper, analysis of microstrip line fed compact C-shape rectangular patch antenna is proposed. The proposed antenna shows dual band operation which depends on notch dimensions as well as length and width of microstrip line. The frequency ratio is obtained to be 4.0 for proposed antenna. The characteristics comparison of reported and proposed antenna parameters has been presented. The theoretical results are compared with simulated results and they are in close agreement.

Keywords - Microstrip Line fed, Notch, Dual-band, Microstrip Patch Antenna (MSA).

1. Introduction
Today the world lives in a completely dependent environment, where the use of modern communication systems is becoming essential in everyday routine. In particular, the field of wireless communications is experiencing unprecedented growth evident from the increase in use of cellular phones, Wireless Local Area Networks (WLAN), Global Positioning Systems (GPS) and Satellite Telephones. Moreover, advancement in electronic warfare revolutionized the wireless communications through cutting edge technologies like Space—Based Radar, Communication Satellites, and Electronic Intelligence. This advancement in wireless communication is due to the rapid development of microwave integrated circuits which embed all the circuit components same circuit board such as resistor, inductor, capacitor and microstrip patch antenna (MSA). MSA is one of important device in the field of communication. Single MSA can be been used in more than application for data communication [1-6]. Only limited research papers has been reported using microstrip strip line fed patch antenna for dualband and multiband operation [7-23]. In these reported papers of microstrip line feeding patch antenna which lacks theoretical analysis, equivalent circuit diagram and has complicated radiating structures.

A novel microstrip line fed compact C-shaped rectangular patch antenna is proposed for dual-band frequency operation. The main objective of this paper is to present theoretical analysis, equivalent circuit diagram and total input impedance of the proposed antenna. The proposed antenna is compared with similar radiating geometry [22]. In the next section, antenna design, analysis of radiating structures, circuit diagram discussion of results and conclusion of proposed antenna are discussed in detail.

2. Antenna Structures and Design Specification

2.1 Antenna Designs
The reported antenna consists of split ring resonator (SRR) and parasitic element which is excited by 50 Ω microstrip line fed [22] and is shown in Fig.1(a). A rectangular C-shape compact microstrip patch antenna is proposed and shown in Fig. 1(b) and design specifications of proposed and reported antennas are given in Table I. The notch is loaded on the rectangular patch which is fed through 50 Ω microstrip line via coaxial cable. Figure 2 shows the current distribution around the notch and edges of patch for lower (0.92 GHz) and higher (3.6 GHz) resonance frequencies.
2.2 Design Specifications

Table I Design Specifications of reported and proposed microstrip patch antennas.

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Value</th>
</tr>
</thead>
<tbody>
<tr>
<td>Thickness of dielectric substrate (H)</td>
<td>1.5 mm</td>
</tr>
<tr>
<td>Permittivity of substrate (( \varepsilon_r ))</td>
<td>2.65</td>
</tr>
<tr>
<td>Loss tangent of substrate (tan( \delta ))</td>
<td>0.0015</td>
</tr>
<tr>
<td>Width of patch (W)</td>
<td>23 mm</td>
</tr>
<tr>
<td>Length of patch (L)</td>
<td>58 mm</td>
</tr>
<tr>
<td>Width of microstrip line (W,)</td>
<td>4.0 mm</td>
</tr>
<tr>
<td>Notch length (( L_{n} ))</td>
<td>26 mm</td>
</tr>
<tr>
<td>Notch width (( L_w ))</td>
<td>14.5 mm</td>
</tr>
<tr>
<td>Length of Microstrip line (( L_s ))</td>
<td>26.5 mm</td>
</tr>
<tr>
<td>Shorting Pin (X_s, Y_s)</td>
<td>(-8.5, 0)</td>
</tr>
<tr>
<td>Gap between the feed patch and parasitic patch (g)</td>
<td>4.0 mm</td>
</tr>
<tr>
<td>Length of SRR’s (S_r)</td>
<td>25.6 mm</td>
</tr>
<tr>
<td>Width of SRR’s (S_w)</td>
<td>25.6 mm</td>
</tr>
<tr>
<td>Width of both SRR’s arm (S_a)</td>
<td>12.65 mm</td>
</tr>
<tr>
<td>Length of SRR’s arm (S_t)</td>
<td>0.5 mm</td>
</tr>
<tr>
<td>Gap between two SRR’s arm (g)</td>
<td>0.5 mm</td>
</tr>
</tbody>
</table>

3. Analysis of compact notch loaded microstrip line fed patch antenna

A rectangular microstrip patch is considered as a parallel combination of resistance (R_1), inductance (L_1), and capacitance (C_1) is shown in Fig.3 (a) and calculated as [23-24],

\[
C_1 = \frac{L W \varepsilon_r \varepsilon_0}{2H} \cos \left( \frac{\pi X_0}{L} \right),
\]

(1)

\[
R_1 = \frac{Q}{\omega C_1}.
\]

(2)

\[
L_1 = \frac{1}{C_1 \omega^2}.
\]

(3)

Quality factor, \( Q = \frac{c \sqrt{\varepsilon_r}}{4 f H} \)

L - Length of rectangular patch
W - Width of rectangular patch
H - Thickness of the substrate material
\( X_0 \) y coordinates of feed point
\( \varepsilon_e \) - effective permittivity of the medium.

3.1 Microstrip line

The microstrip line of the rectangular strip is considered parallel combination of inductance L and capacitance C. The equivalent circuit of the microstrip line rectangular patch is shown in Fig. 3(b), where \( L_1 \) and \( C_1 \) are inductance and capacitance of strip [24-25],

\[
L_1 = 100.H \left( 4 \sqrt{W_s / H} - 4.21 \right) nH.
\]

(4)

\[
C_1 = W_s[(9.5 \varepsilon_e + 1.25)W / H + 5.2 \varepsilon_e + 7.0] \mu F.
\]

(5)

Resonance frequency of the microstrip line antenna is given as

\[
f = c / 2L_1 \sqrt{\varepsilon_r}.
\]

(6)

where

\[
\varepsilon_r = 1/2[(\varepsilon_e + 1) + (\varepsilon_e - 1)(1 - 12.H / W_s)^{-1/2}] .
\]

\[
L_1 = L_1 + \Delta L_1.
\]

\( \varepsilon_r \) - Effective dielectric constant
\( \Delta L_1 \) - Effective increase in length of strip

\[
\Delta L_1 = H(0.412 \varepsilon_e + 0.3)(W / H + 0.264) \varepsilon_e - 0.258(W / H + 0.8).
\]

\( \varepsilon_e \) - Dielectric constant,

The characteristic impedance of microstrip line can be given as,

\[
Z = j \omega L_1 + \frac{1}{j \omega C_1 + \frac{1}{j \omega L_1}}
\]

(7)

3.2 Loading of notch

When a notch is etched on the patch, current distribution of radiating structure changes in comparison to the normal radiating patch. Thus due to this two current flows of different length, one current flow normal to the patch and resonates at the design
frequency of the initial patch, and other current flows around the notch results in second resonance frequency and is shown in Fig. 2. Therefore, this perturbation modifies the equivalent circuit of the initial patch as an additional series inductance ($\Delta L$) and series capacitance ($\Delta C$) [26-27] is added, as shown in Fig. 3(c) the equivalent circuit of notch.

$$C_n = \frac{- (C_2 + C_1) + \sqrt{(C_2 + C_1)^2 + (1 - 1/k^2) C_2 C_1 k^2}}{2},$$  \hspace{1cm} (12)

The mutual impedance can be given as,

$$Z_m = j \omega L_n + \frac{1}{j \omega C_n}$$  \hspace{1cm} (13)

where

$$L_2 = \frac{L_1 \Delta L}{L_1 + \Delta L}, \quad C_2 = C_1 + \Delta C,$$

$$k_n = \frac{1}{\sqrt{Q_1 Q_2}},$$

$$Q_1 = R_1 \sqrt{\frac{C_1}{L_1}},$$

$$Q_2 = R_2 \sqrt{\frac{C_1}{L_2}}.$$  

$Q_1$ and $Q_2$ are quality factor for both the resonators.

3.3 Loading of shorting pin

On loading shorting pin on the patch, a parallel inductance $L_s$ is added on the patch, the equivalent circuit of rectangular patch antenna with shorting pin is shown in Fig 4. The value of $L_n$ [24] can be given as,

$$L_n = \frac{\eta WL}{2 \pi c} \ln \left[ \frac{4 c}{E \omega d \sqrt{\mu \eta}} \right]$$  \hspace{1cm} (14)

where,

$c$ - speed of light,

d - diameter of shorting pin,

$E$ - Euler constant, $\eta = 120 \pi$.

The impedance of shorting pin loaded patch from fig. 4, is given as

$$Z_m = \frac{1}{R_1} + \frac{1}{j \omega L_1} + \frac{1}{j \omega L_s} + j \omega C_n$$  \hspace{1cm} (15)

The value of $R_2$ resistance [11] after cutting the notch is calculated. $L_n$ and $C_m$ are mutual inductance and capacitance [26-27] between the two resonators which is given as,

$$L_n = k_n^2 (L_1 + L_2) + k_n^2 (L_1 + L_2)^2 + 4k_n^2 (1 - k_n^2) L_1 L_2 k_n$$  \hspace{1cm} (11)

$$C_m = \frac{\sqrt{(C_2 + C_1)^2 + (1 - 1/k^2) C_2 C_1 k^2}}{2},$$  \hspace{1cm} (12)

The mutual impedance can be given as,

$$Z_m = j \omega L_n + \frac{1}{j \omega C_n},$$  \hspace{1cm} (13)

where

$$L_2 = \frac{L_1 \Delta L}{L_1 + \Delta L}, \quad C_2 = C_1 + \Delta C,$$

$$k_n = \frac{1}{\sqrt{Q_1 Q_2}},$$

$$Q_1 = R_1 \sqrt{\frac{C_1}{L_1}},$$

$$Q_2 = R_2 \sqrt{\frac{C_1}{L_2}}.$$  

$Q_1$ and $Q_2$ are quality factor for both the resonators.
Now using equation (16) the total input impedance of the proposed antenna and reported antenna respectively. Their various antenna parameters such as reflection coefficient, VSWR and return loss can be calculated as,

\[
\text{Reflection Coefficient } \Gamma = \frac{Z - Z_{in}}{Z + Z_{in}},
\]

where 
\( Z \) is the input impedance of the microstrip fed (50 Ω) and 
\( Z \) is the distance of an arbitrary point.

\[ VSWR = \frac{1 + \Gamma}{1 - \Gamma}, \]

and 
\( RL = 20 \log |\Gamma| \)

\[ E_{\theta} = -jkWv \frac{\sin \phi}{\pi} \left( \frac{kW}{\sin \phi} \right) \left( \frac{kW}{2 \sin \phi} \right) \cos \phi 
\]

\[ 0 \leq \phi \leq \pi/2 \]

(17)

\[ E_{\phi} = \frac{jWv}{\pi} \cos \phi \left( \frac{kW}{\sin \phi} \right) \frac{\cos \phi}{\sin \phi} \frac{kW}{2 \sin \phi} \cos \phi \]

\[ 0 \leq \phi \leq \pi/2 \]

(18)

where , 
\( V \) is radiating edge voltage 
\( r \) is the distance of an arbitrary point. 
\( k = k_0 \sqrt{\varepsilon_r} \) 
\( k_0 = \frac{2\pi}{\lambda} \)

Similarly for two dielectric layers microstrip patch antenna.
\( k = k_0 \sqrt{\varepsilon_{eff}} \),

where 
\( \varepsilon_{eff} \) is the effective permittivity for driven patch.
\( E_{\text{total}} = |E(\theta)|^2 + |E(\phi)|^2 \)

5. Discussion of Results

Figure 5 shows the comparison between the reported and proposed antenna. It is observed that both antennas give dualband operation. The reported and proposed antenna resonated at 0.9/1.8 GHz and 0.9/3.6 GHz respectively and these can be utilized for wireless communication. Reason behind the comparison of the reported antenna is that the reported antenna has some limitation that can be overcome by the proposed antenna such as reduced in area, polarization and gain. Complete comparison details of both antennas are given in Table 2.

Figure 6 shows, the variation of reflection coefficient with frequency for microstrip line fed C-shape compact rectangular patch antenna. It is observed that the simulated and theoretical results are in good agreement. Frequency ratio of simulated and theoretical results is obtained as 3.9 and 4.0 respectively.

From Fig. 7, it is observed that on increasing the thickness of dielectric substrate \( H = 1.5 \text{mm} \) to \( 2.5 \text{mm} \) the frequency ratio increases from 4.0 to 5.8 whereas decreasing the thickness of dielectric substrate \( H = 1.5 \text{mm} \) to \( 0.5 \text{mm} \) the frequency ratio of proposed antenna decreases from 4.0 to 1.97.

Figure 8 shows the variation of reflection coefficient with frequency on decreasing \( W_s = 4 \text{ mm} \) to \( 2 \text{ mm} \) and increasing \( W_s = 4 \text{ mm} \) to \( 8 \text{ mm} \) the width of microstrip line, there is no change in the frequency ratio whereas slight shifting is observed at lower and upper resonance frequencies.

From Fig. 9, it is observed that on increasing the length microstrip line \( L_s = 21.6 \text{mm} \) to \( 29.6 \text{mm} \) higher resonance frequency shift towards lower resonance side whereas no change has been observed at lower resonance frequency. Thus decrease in frequency ratio is observed from 4.0 to 3.4.

Figure 10 shows the variation of reflection coefficient with frequency on decreasing notch width \( N_w = 26 \text{ mm} \) to \( 17 \text{ mm} \) higher resonance frequency shift toward higher side with increase in frequency ratio from 4.0 to 5.39.

From Fig.11 shows the radiation pattern at lower (0.92 GHz) and higher (3.6 GHz) resonance frequency and antenna shows linear polarization.
Table-III Characteristics of Antennas

<table>
<thead>
<tr>
<th>Antenna Type</th>
<th>Band (GHz)</th>
<th>Bandwidth (MHz)</th>
<th>Gain (dBi)</th>
<th>Polarization</th>
<th>Frequency Ratio</th>
</tr>
</thead>
<tbody>
<tr>
<td>Inset fed microstrip patch antenna with parasitic SRR’s [22]</td>
<td>0.874-0.943</td>
<td>69 MHz</td>
<td>1.8</td>
<td>Circular</td>
<td>2.0</td>
</tr>
<tr>
<td>Proposed inset fed microstrip patch antenna with notch</td>
<td>0.910-0.980</td>
<td>70 MHz</td>
<td>3.7</td>
<td>Linear</td>
<td>4.0</td>
</tr>
</tbody>
</table>

Figure 5 Comparison between theoretical and simulated results[28] of proposed antenna.

Figure 6 Variation of reflection coefficient (dB) with frequency on varying height (H) of the proposed antenna.

Figure 7 Variation of reflection coefficient (dB) with frequency on varying width of microstrip (Ws) of the proposed antenna.

Figure 8 Variation of reflection coefficient (dB) with frequency on varying length of microstrip (Ls) of the proposed antenna.

Figure 9 Variation of reflection coefficient (dB) with frequency on varying width of notch (Nw) of the proposed antenna.
6. Conclusion

The proposed microstrip line fed compact C-shape rectangular patch antenna is in close agreement with simulated and theoretical results. The frequency ratio of the proposed antenna depends on the notch width and length. The proposed antenna has frequency ratio 4.0 and maximum gain 3.7 dBi. The proposed antennas can be utilized for mobiles and down linking for satellite communications.

References


